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SANYO Semiconductor (U.S.A) Corporation 2SA1669-TB-E

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Datasheet of 2SA1669-TB-E - TRANS PNP 15V 50MA 3CP

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Ordering number: ENN2972

PNP Epitaxial Planar Silicon Transistors



2SA1669

High-Frequency Amplifier Applications

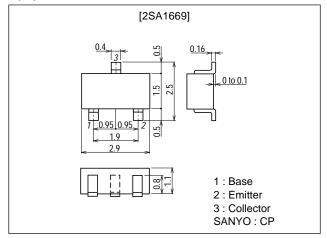
Features

· High cutoff frequnecy : f_T =3.0GHz typ.

High power gain
Small noise figure
MAG=11dB typ (f=0.9GHz)
NF=2.0dB typ (f=0.9GHz)

Package Dimensions

unit:mm 2018B



Specifications

Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	VCBO		-20	V
Collector-to-Emitter Voltage	VCEO		-15	V
Emitter-to-Base Voltage	V _{EBO}		-3	٧
Collector Current	lС		– 50	mA
Collector Dissipation	PC		250	mW
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta = 25°C

Parameter	Symbol	Conditions		Ratings			
Farameter	Symbol	Conditions	min	typ	max	Unit	
Collector Cutoff Current	I _{CBO}	V _{CB} =-15V, I _E =0			-0.1	μA	
Emitter Cutoff Current	I _{EBO}	V _{EB} =-2V, I _C =0			-0.1	μA	
DC Current Gain	hFE	V _{CE} =-10V, I _C =-5mA	15				
Gain-Bandwidth Product	fT	V _{CE} =-10V, I _C =-5mA	1.5	3.0		GHz	
Collector Output Capacitance	C _{ob}	V _{CB} =-10V, f=1MHz		1.0	1.5	pF	
Reverse Transfer Capacitance	C _{re}	V _{CB} =-10V, f=1MHz		0.7		pF	
Forward Transfer Gain	S21e ²	V _{CE} =-10V, I _C =-5mA, f=0.9GHz	5.0			dB	
Maximum Available Power Gain	MAG	V _{CE} =-10V, I _C =-5mA, f=0.9GHz		11		dB	
Noise Figure	NF	V _{CF} =-10V, I _C =-3mA, f=0.9GHz		2.0		dB	

Note) Marking: DB

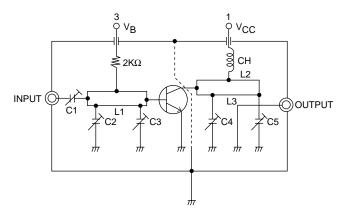
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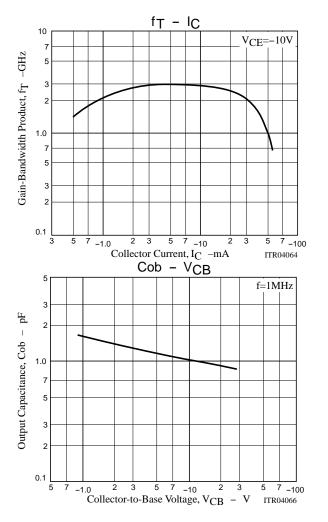
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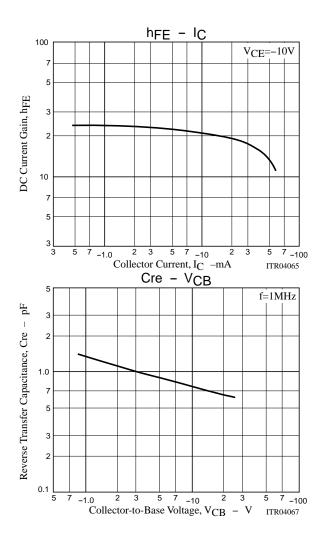
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NF Test Circuit

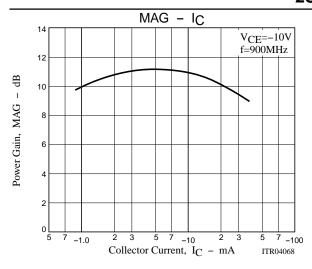


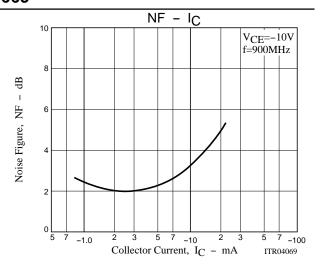
	900MHz					
C1	to 5pF					
C2	to 10pF					
C3	to 10pF					
C4	to 10pF					
C5	to 10pF					
L1	W≈1.5mm, 1≈25mm strip line					
L2	W≈4mm, 1≈25mm strip line					
L3	0.5ø, 1≈40mm					
СН	2t+bead core					

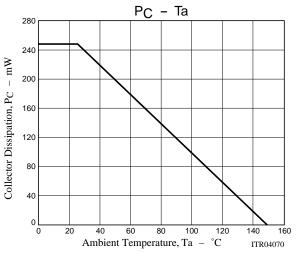




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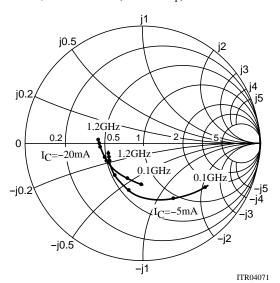




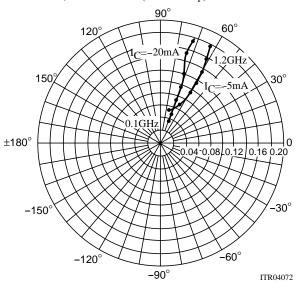


S parameter

S11e: V_{CE}=-10V f=100MHz, 200 to 1200MHz(200MHz step)



$$\begin{split} &\text{S12e}: \text{V}_{CE}\text{=-}10\text{V} \\ &\text{f=100MHz, 200 to 1200MHz(200MHz step)} \end{split}$$



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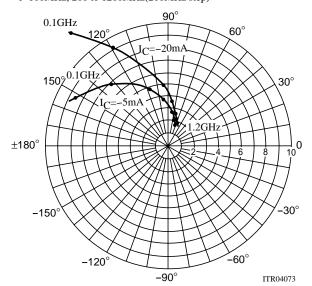
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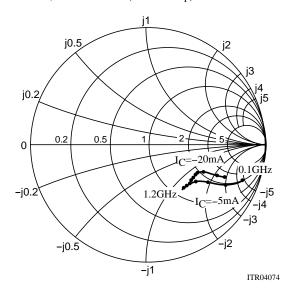
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S parameter

S21e : V_{CE}=-10V f=100MHz, 200 to 1200MHz(200MHz step)



 $\begin{array}{l} S22e: V_{CE} \!\!=\!\! -10V \\ f \!\!=\!\! 100 MHz, 200 \text{ to } 1200 MHz (200 MHz \text{ step}) \end{array}$



S parameter (Common emitter)

 V_{CE} =-10V, I_{C} =-5mA, Z_{O} =50 Ω

Freq (MHz)	S ₁₁	∠S ₁₁	S ₂₁	∠S ₂₁	S ₁₂	∠S ₁₂	S ₂₂	∠S ₂₂
100	0.707	-33.1	8.215	151.1	0.043	68.6	0.856	-19.8
200	0.589	-60.3	6.763	132.2	0.059	62.0	0.761	-25.4
400	0.435	-104.7	4.810	106.5	0.089	56.4	0.584	-34.2
600	0.373	-128.1	3.503	93.2	0.110	57.3	0.508	-36.6
800	0.349	-144.4	2.728	83.4	0.130	59.5	0.474	-39.0
900	0.346	-150.1	2.492	80.0	0.142	60.9	0.464	-40.3
1000	0.344	-155.4	2.266	76.8	0.154	61.4	0.459	-41.7
1200	0.340	-163.6	1.971	70.6	0.176	62.1	0.452	-45.2

V_{CE} =-10V, I_{C} =-20mA, Z_{O} =50 Ω

Freq (MHz)	S ₁₁	∠S ₁₁	S ₂₁	∠S ₂₁	S ₁₂	∠S ₁₂	S ₂₂	∠ S ₂₂
100	0.348	-92.8	12.039	129.4	0.031	67.3	0.727	-22.9
200	0.330	-116.7	9.073	118.2	0.041	66.0	0.634	-24.8
400	0.350	-151.2	4.962	95.1	0.068	67.7	0.510	-26.5
600	0.353	-164.5	3.408	84.4	0.093	69.9	0.481	-28.1
800	0.360	-172.9	2.591	76.4	0.118	71.6	0.470	-31.1
900	0.366	-176.2	2.346	73.3	0.131	72.0	0.467	-32.9
1000	0.371	-178.4	2.142	70.8	0.146	71.8	0.467	-34.8
1200	0.379	176.2	1.851	65.2	0.171	71.1	0.466	-39.1



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